

30V, N-Channel NexFET™ Power MOSFETs

Check for Samples: [CSD17301Q5A](#)

FEATURES

- Optimized for 5V Gate Drive
- Ultralow Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

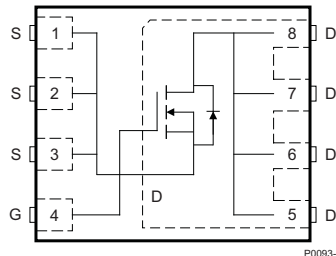
APPLICATIONS

- Notebook Point of Load
- Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems
- Optimized for Synchronous FET Applications

DESCRIPTION

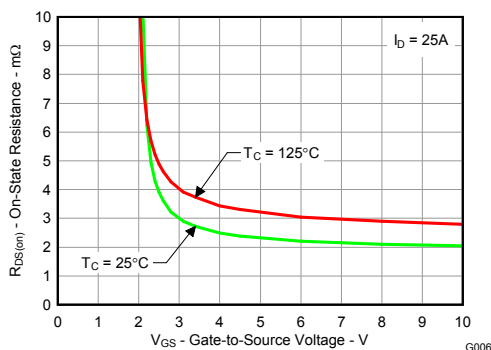
The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications, and optimized for 5V gate drive applications.

Top View



P0093-01

$R_{DS(on)}$ vs V_{GS}



PRODUCT SUMMARY

| | | | |
|--------------|-------------------------------|-----------------|--------|
| V_{DS} | Drain to Source Voltage | 30 | V |
| Q_g | Gate Charge Total (4.5V) | 19 | nC |
| Q_{gd} | Gate Charge Gate to Drain | 4.3 | nC |
| $R_{DS(on)}$ | Drain to Source On Resistance | $V_{GS} = 3V$ | 2.9 mΩ |
| | | $V_{GS} = 4.5V$ | 2.3 mΩ |
| | | $V_{GS} = 8V$ | 2 mΩ |
| $V_{GS(th)}$ | Threshold Voltage | 1.1 | V |

ORDERING INFORMATION

| Device | Package | Media | Qty | Ship |
|-------------|---------------------------------|--------------|------|---------------|
| CSD17301Q5A | SON 5-mm × 6-mm Plastic Package | 13-inch reel | 2500 | Tape and Reel |

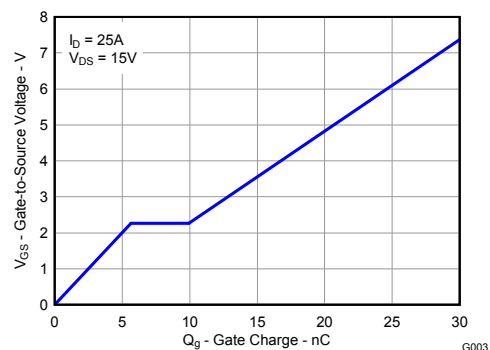
ABSOLUTE MAXIMUM RATINGS

| $T_A = 25^\circ\text{C}$ unless otherwise stated | | VALUE | UNIT |
|--|--|------------|------------------|
| V_{DS} | Drain to Source Voltage | 30 | V |
| V_{GS} | Gate to Source Voltage | +10 / -8 | V |
| I_D | Continuous Drain Current, $T_C = 25^\circ\text{C}$ | 100 | A |
| | Continuous Drain Current ⁽¹⁾ | 28 | A |
| I_{DM} | Pulsed Drain Current, $T_A = 25^\circ\text{C}$ ⁽²⁾ | 118 | A |
| P_D | Power Dissipation ⁽¹⁾ | 3.2 | W |
| T_J, T_{STG} | Operating Junction and Storage Temperature Range | -55 to 150 | $^\circ\text{C}$ |
| E_{AS} | Avalanche Energy, single pulse $I_D = 91\text{A}, L = 0.1\text{mH}, R_G = 25\Omega$ | 414 | mJ |

(1) Typical $R_{\theta JA} = 39^\circ\text{C/W}$ on 1in² Cu (2 oz) on 0.060" thick FR4 PCB.

(2) Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$

GATE CHARGE



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ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT | |
|-------------------------|----------------------------------|--|------|-----|------|------|----|
| Static Characteristics | | | | | | | |
| BV _{DSS} | Drain to Source Voltage | V _{GS} = 0V, I _D = 250μA | 30 | | | V | |
| I _{DSS} | Drain to Source Leakage Current | V _{GS} = 0V, V _{DS} = 24V | 1 | | | μA | |
| I _{GSS} | Gate to Source Leakage Current | V _{DS} = 0V, V _{GS} = +10/-8V | 100 | | | nA | |
| V _{GS(th)} | Gate to Source Threshold Voltage | V _{DS} = V _{GS} , I _D = 250μA | 0.9 | 1.1 | 1.55 | V | |
| R _{DS(on)} | Drain to Source On Resistance | V _{GS} = 3V, I _D = 25A | 2.9 | | | 3.7 | mΩ |
| | | V _{GS} = 4.5V, I _D = 25A | 2.3 | | | 3 | mΩ |
| | | V _{GS} = 8V, I _D = 25A | 2 | | | 2.6 | mΩ |
| | | | | | | | |
| g _{fs} | Transconductance | V _{DS} = 15V, I _D = 25A | 149 | | | S | |
| Dynamic Characteristics | | | | | | | |
| C _{iss} | Input Capacitance | V _{GS} = 0V, V _{DS} = 15V, f = 1MHz | 2660 | | | 3480 | pF |
| C _{oss} | Output Capacitance | | 1420 | | | 1850 | pF |
| C _{rss} | Reverse Transfer Capacitance | | 80 | | | 105 | pF |
| R _G | Series Gate Resistance | | 1.3 | | | 2.6 | Ω |
| Q _g | Gate Charge Total (4.5V) | V _{DS} = 15V, I _D = 25A | 19 | | | 25 | nC |
| Q _{gd} | Gate Charge Gate to Drain | | 4.3 | | | | nC |
| Q _{gs} | Gate Charge Gate to Source | | 5.7 | | | | nC |
| Q _{g(th)} | Gate Charge at V _{th} | | 2.9 | | | | nC |
| Q _{oss} | Output Charge | V _{DS} = 14V, V _{GS} = 0V | 35 | | | | nC |
| t _{d(on)} | Turn On Delay Time | V _{DS} = 15V, V _{GS} = 4.5V, I _D = 25A R _G = 2Ω | 10.7 | | | | ns |
| t _r | Rise Time | | 16.2 | | | | ns |
| t _{d(off)} | Turn Off Delay Time | | 28 | | | | ns |
| t _f | Fall Time | | 10.5 | | | | ns |
| Diode Characteristics | | | | | | | |
| V _{SD} | Diode Forward Voltage | I _{SD} = 25A, V _{GS} = 0V | 0.8 | | | 1 | V |
| Q _{rr} | Reverse Recovery Charge | V _{DD} = 14V, I _F = 25A, di/dt = 300A/μs | 50 | | | | nC |
| t _{rr} | Reverse Recovery Time | | 33 | | | | ns |

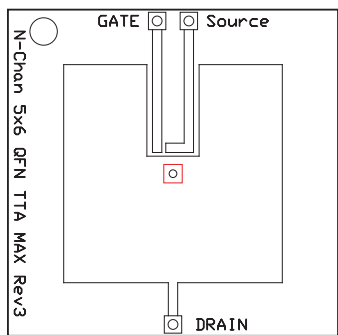
THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

| PARAMETER | | MIN | TYP | MAX | UNIT |
|------------------|---|-----|-----|-----|------|
| R _{θJC} | Thermal Resistance Junction to Case ⁽¹⁾ | | | 2.2 | °C/W |
| R _{θJA} | Thermal Resistance Junction to Ambient ^{(1) (2)} | | | 49 | °C/W |

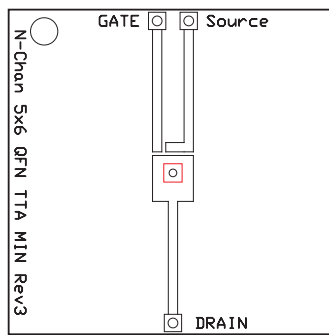
(1) R_{θJC} is determined with the device mounted on a 1 inch square 2 oz. Cu pad on a 1.5 × 1.5 in 0.060 inch thick FR4 board. R_{θJC} is specified by design while R_{θJA} is determined by the user's board design.

(2) Device mounted on FR4 Material with 1 inch² of 2 oz. Cu.



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Max $R_{\theta JA} = 49^{\circ}\text{C/W}$
when mounted on
1inch² of 2 oz. Cu.

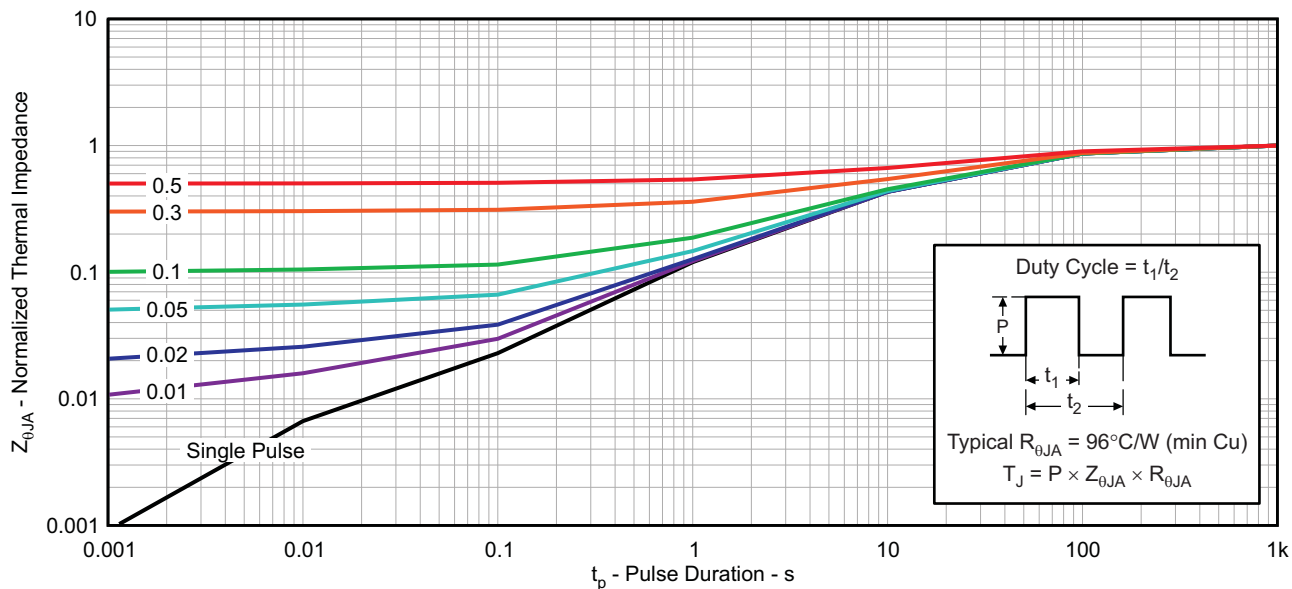


M0137-02

Max $R_{\theta JA} = 120^{\circ}\text{C/W}$
when mounted on
minimum pad area of 2
oz. Cu.

TYPICAL MOSFET CHARACTERISTICS

($T_A = 25^{\circ}\text{C}$ unless otherwise stated)



G012

Figure 1. Transient Thermal Impedance

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

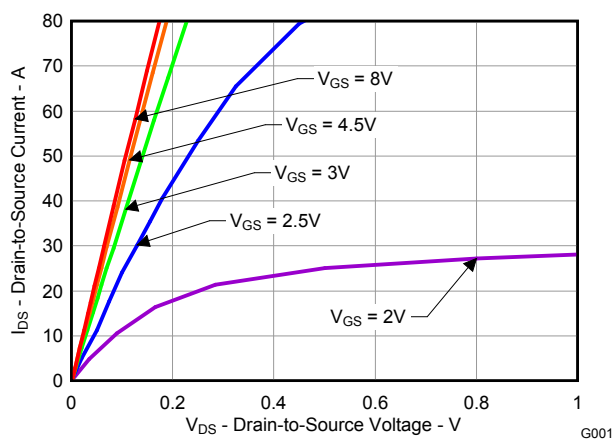


Figure 2. Saturation Characteristics

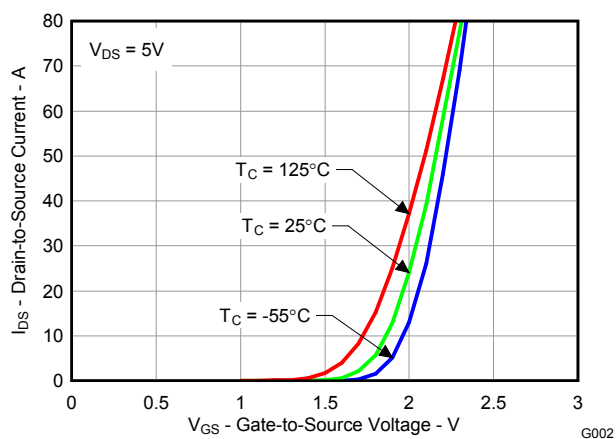


Figure 3. Transfer Characteristics

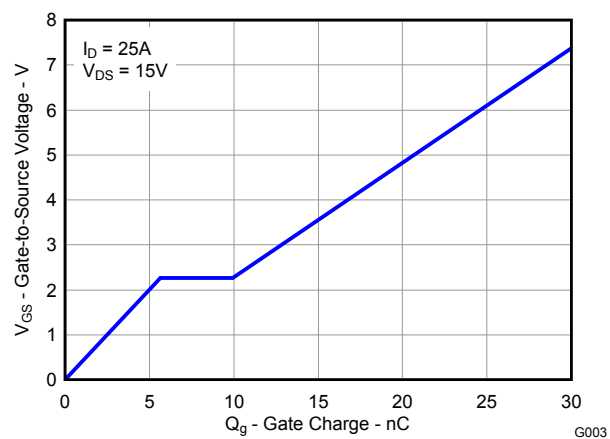


Figure 4. Gate Charge

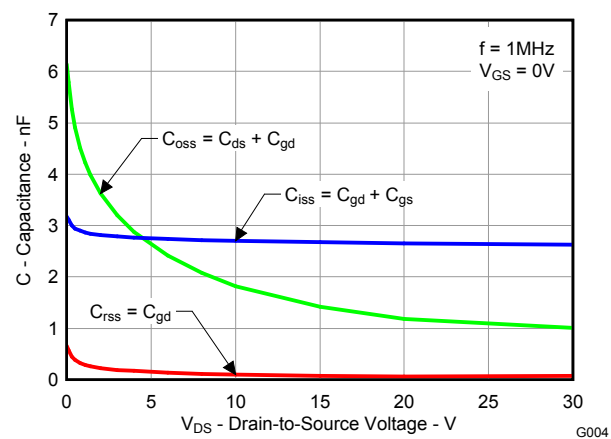


Figure 5. Capacitance

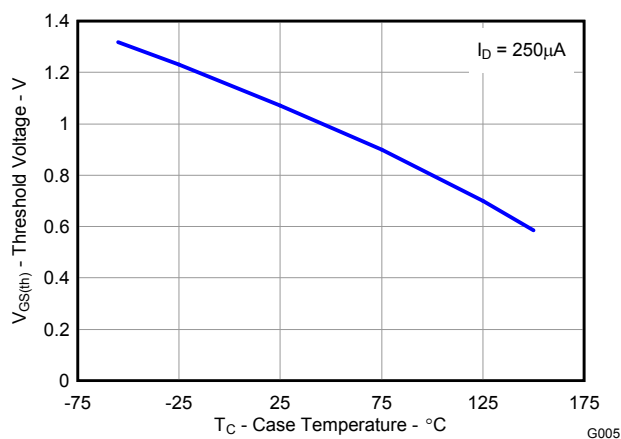


Figure 6. Threshold Voltage vs. Temperature

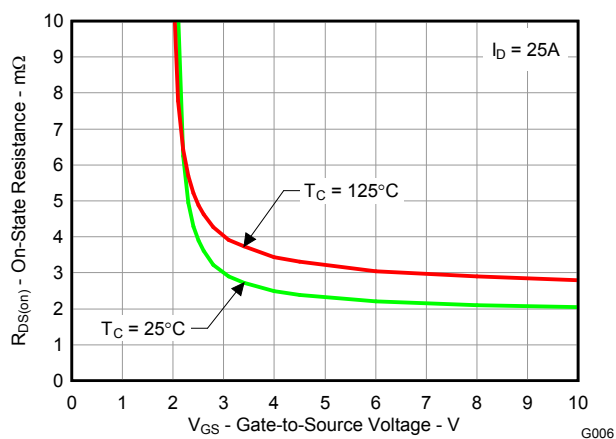


Figure 7. On Resistance vs. Gate Voltage

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

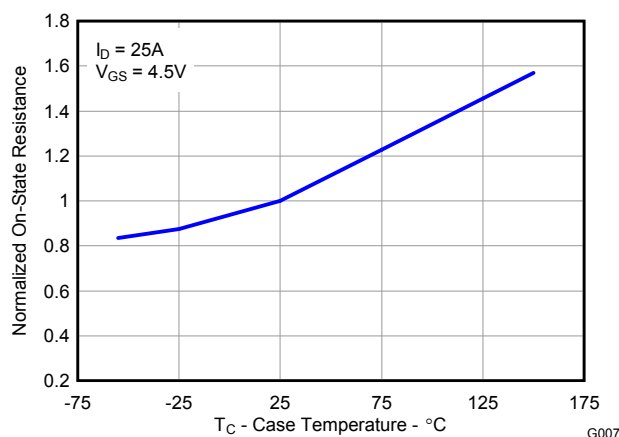


Figure 8. On Resistance vs. Temperature

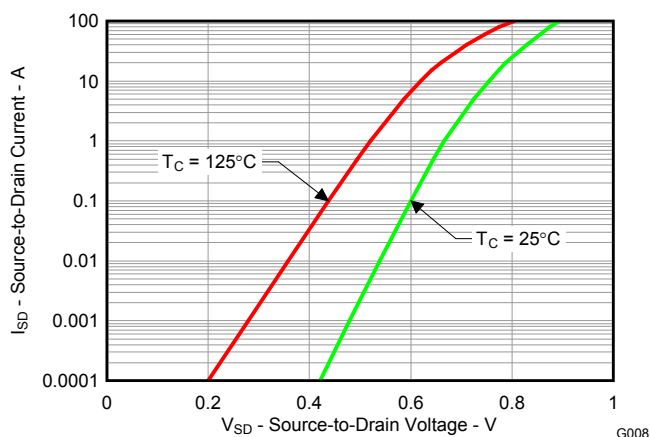


Figure 9. Typical Diode Forward Voltage

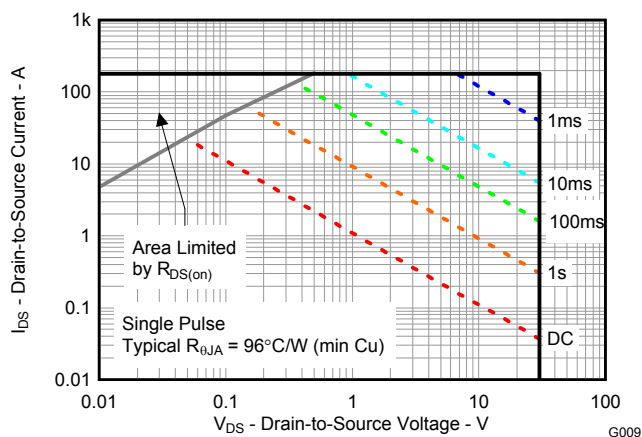


Figure 10. Maximum Safe Operating Area

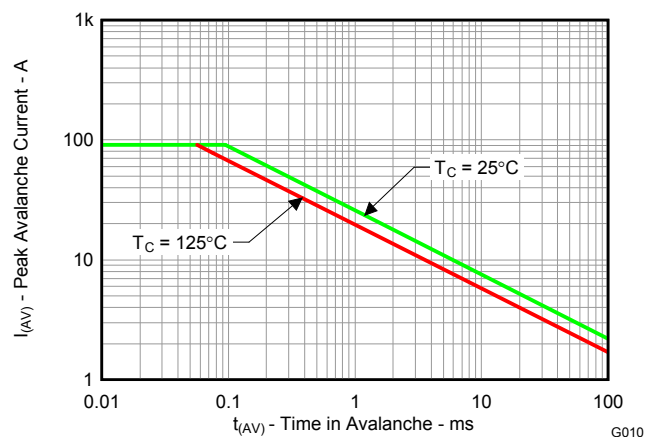


Figure 11. Single Pulse Unclamped Inductive Switching

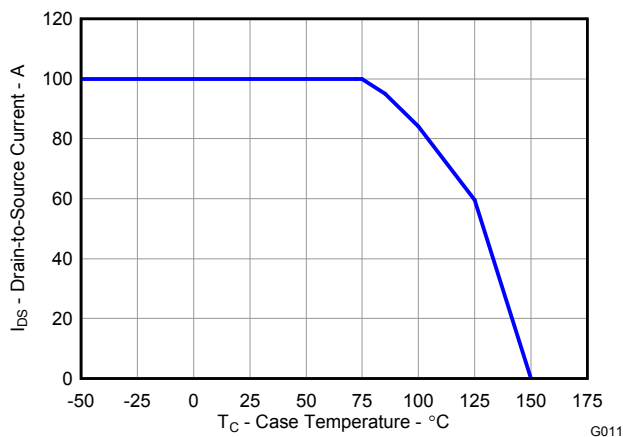
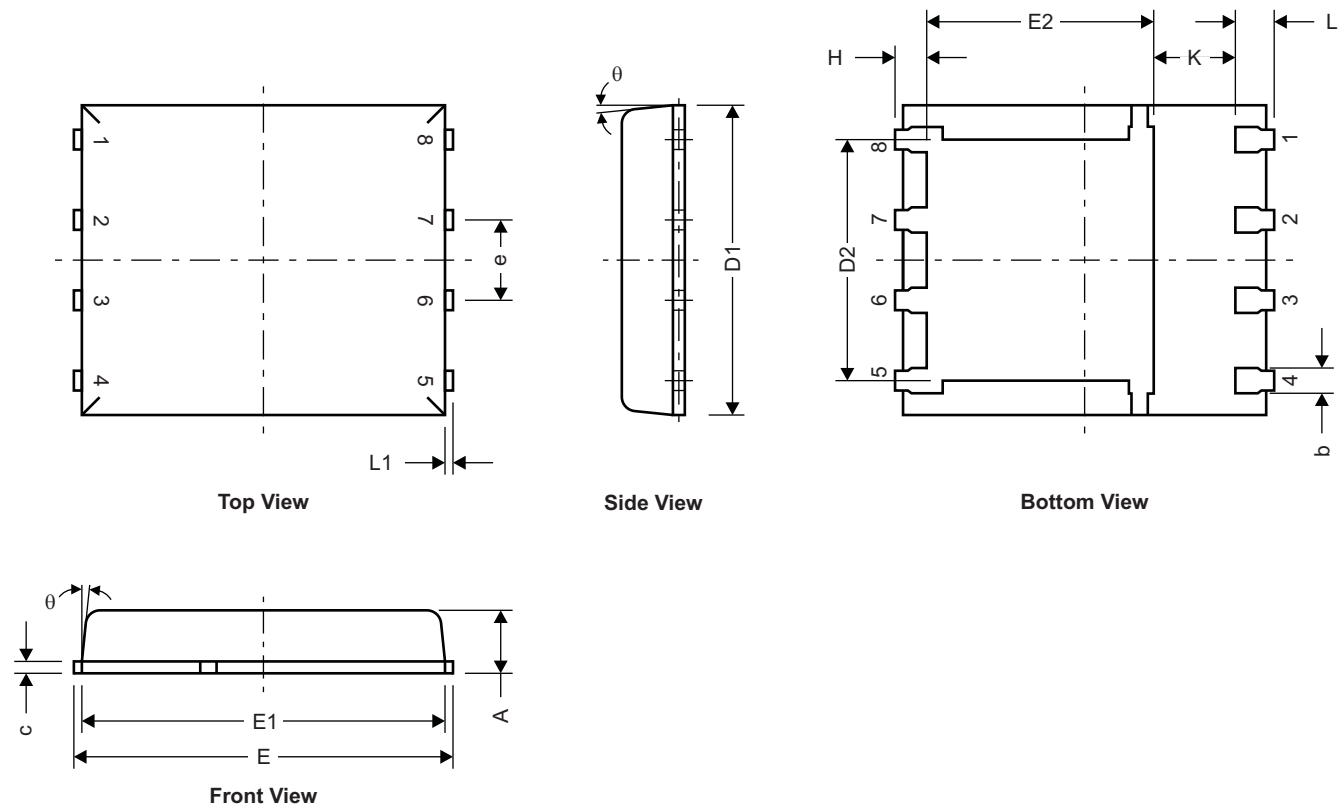


Figure 12. Maximum Drain Current vs. Temperature

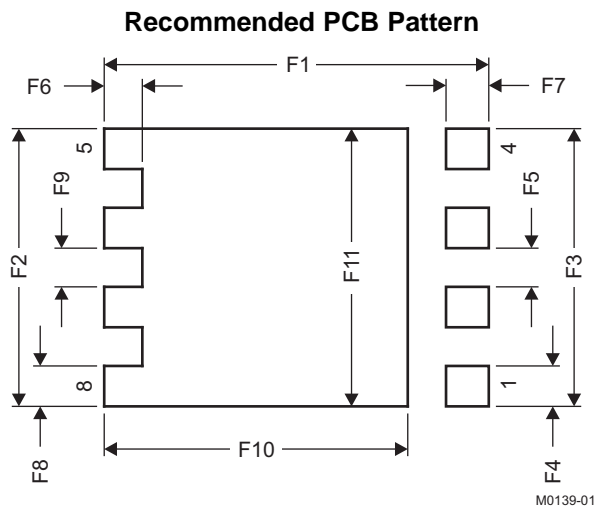
MECHANICAL DATA

Q5A Package Dimensions



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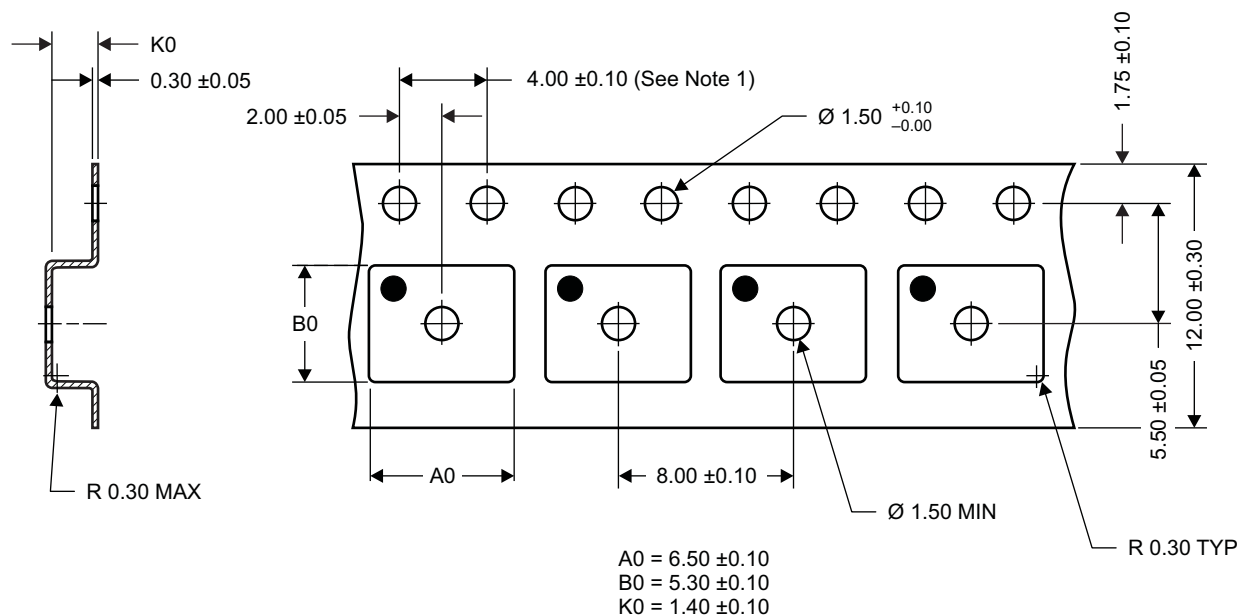
| DIM | MILLIMETERS | | |
|----------|-------------|------|------|
| | MIN | NOM | MAX |
| A | 0.90 | 1.00 | 1.10 |
| b | 0.33 | 0.41 | 0.51 |
| c | 0.20 | 0.25 | 0.30 |
| D1 | 4.80 | 4.90 | 5.00 |
| D2 | 3.61 | 3.81 | 3.96 |
| E | 5.90 | 6.00 | 6.10 |
| E1 | 5.70 | 5.75 | 5.80 |
| E2 | 3.38 | 3.58 | 3.78 |
| e | 1.27 BSC | | |
| H | 0.41 | 0.51 | 0.61 |
| K | 1.10 | | |
| L | 0.51 | 0.61 | 0.71 |
| L1 | 0.06 | 0.13 | 0.20 |
| θ | 0° | | 12° |



| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|--------|-------|
| | MIN | MAX | MIN | MAX |
| F1 | 6.205 | 6.305 | 0.244 | 0.248 |
| F2 | 4.46 | 4.56 | 0.176 | 0.18 |
| F3 | 4.46 | 4.56 | 0.176 | 0.18 |
| F4 | 0.65 | 0.7 | 0.026 | 0.028 |
| F5 | 0.62 | 0.67 | 0.024 | 0.026 |
| F6 | 0.63 | 0.68 | 0.025 | 0.027 |
| F7 | 0.7 | 0.8 | 0.028 | 0.031 |
| F8 | 0.65 | 0.7 | 0.026 | 0.028 |
| F9 | 0.62 | 0.67 | 0.024 | 0.026 |
| F10 | 4.9 | 5 | 0.193 | 0.197 |
| F11 | 4.46 | 4.56 | 0.176 | 0.18 |

For recommended circuit layout for PCB designs, see application note [SLPA005 – Reducing Ringing Through PCB Layout Techniques](#).

Q5A Tape and Reel Information



Notes:

- 10-sprocket hole-pitch cumulative tolerance ± 0.2
- Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- Material: black static-dissipative polystyrene
- All dimensions are in mm (unless otherwise specified)
- A0 and B0 measured on a plane 0.3mm above the bottom of the pocket
- MSL1 260°C (IR and convection) PbF reflow compatible

Package Marking Information

Location

1st Line

CSD = Fixed Characters

NNNNN = Product Code

2nd Line (Date Code)

YY = Last 2 digits of the Year

WW = 2-digit Work Week

C = Country of Origin

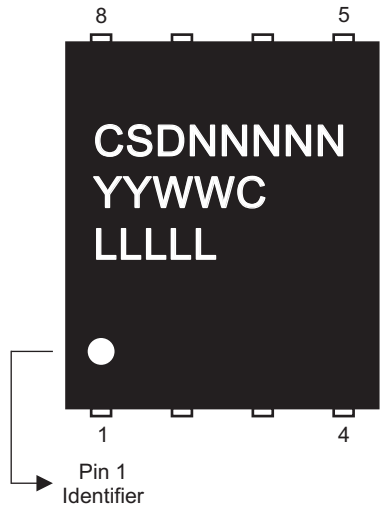
> Philippines = P

> Taiwan = T

> China = C

3rd Line

LLLLL = Last 5 digits of the Wafer Lot #



M0136-01

REVISION HISTORY

| Changes from Original (January) to Revision A | Page |
|---|------|
| • Changed the Abs Max Ratings table, Avalanche Energy, single pulse From: $I_D = 85A$, $L = 0.1mH$, $R_G = 25\Omega$ Value = 361 To: $I_D = 91A$, $L = 0.1mH$, $R_G = 25\Omega$ Value = 414 | 1 |
| • Changed Figure 11 | 5 |

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